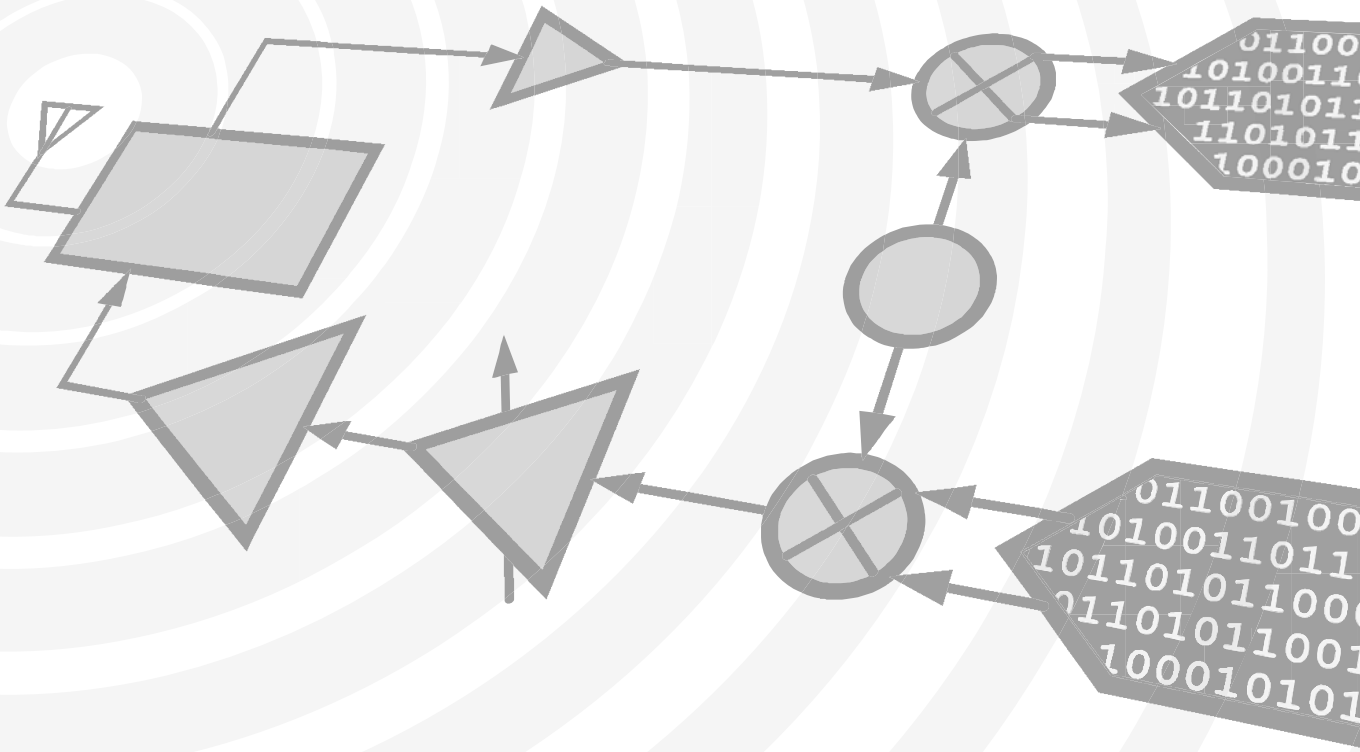
ANALOG DEVICES

Hittite MICROWAVE PRODUCTS FROM ANALOG DEVICES

Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



www.analog.com

www.hittite.com

HMC626A* Product Page Quick Links

Last Content Update: 08/30/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

- HMC626ALP5 Evaluation Board

Documentation

Data Sheet

- HMC626A Data Sheet

Reference Materials

Quality Documentation

- Semiconductor Qualification Test Report: PHEMT-J (QTR: 2013-00285)

Design Resources

- HMC626A Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

Discussions

View all HMC626A EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

* This page was dynamically generated by Analog Devices, Inc. and inserted into this data sheet. Note: Dynamic changes to the content on this page does not constitute a change to the revision number of the product data sheet. This content may be frequently modified.

THIS PAGE INTENTIONALLY LEFT BLANK

HMC626ALP5E

v00.1212

0.5 dB LSB GaAs MMIC 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 1 GHz

Typical Applications

The HMC626ALP5E is ideal for:

- IF & RF Applications
- Cellular/3G Infrastructure
- WiBro / WiMAX / 4G
- Microwave Radio & VSAT
- Test Equipment and Sensors

Features

+8.5 dB to +40 dB Gain Control in 0.5 dB Steps

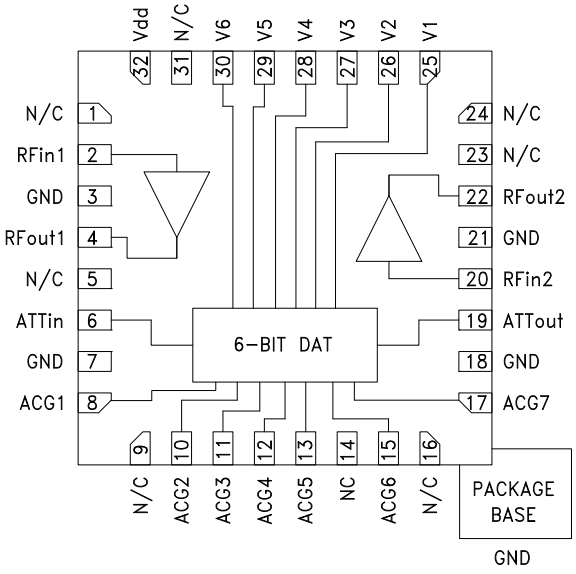
High Output IP3: +36 dBm

±0.25 dB Typical Gain Step Error

Single +5V Supply

32 Lead 5x5 mm SMT Package: 25 mm^2

Functional Diagram



General Description

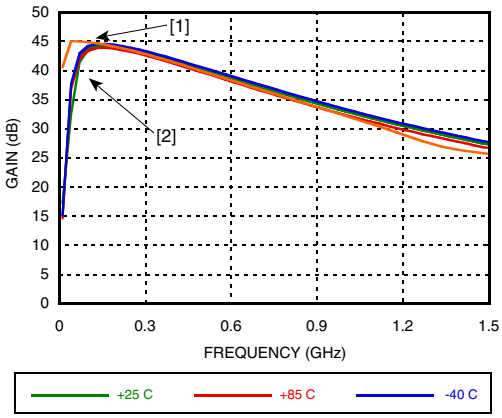
The HMC626ALP5E is a digitally controlled variable gain amplifier which operates from DC to 1 GHz, and can be programmed to provide anywhere from 8.5 dB, to 40 dB of gain, in 0.5 dB steps. The HMC626ALP5E delivers noise figure of 2.8 dB in its maximum gain state, with output IP3 of up to +36 dBm in any state. This single positive control line per bit digital VGA incorporates off chip AC ground capacitors for near DC operation, making it suitable for a wide variety of RF and IF applications. The HMC626ALP5E is housed in a RoHS compliant 5x5 mm QFN leadless package, and requires no external matching components. A serial control version of this product is available as the HMC681ALP5E.

Electrical Specifications, T_A = +25° C, Vdd = Vs= +5V, Vctl= 0/ +5V

Parameter	Frequency	Min.	Typ.	Max.	Units
Gain (Maximum Gain State)	DC - 0.5 GHz 0.5 - 1.0 GHz	37 30	42.5 35.0		dB dB
Gain Control Range			31.5		dB
Input Return Loss			20		dB
Output Return Loss			15		dB
Gain Setting Accuracy: (Referenced to Maximum Gain State) All Gain States	0.05 - 1.0 GHz	± (0.15 + 3% of Relative Gain Setting) Max.			dB
Output Power for 1 dB Compression	DC - 1.0 GHz		20		dBm
Output Third Order Intercept Point (Two-Tone Output Power= 5 dBm Each Tone)	DC - 1.0 GHz		36		dBm
Noise Figure	DC - 1.0 GHz		2.8		dB
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)	DC - 1.0 GHz		 100 120		 ns ns
Total Supply Current (Idd + 2*Is)	DC - 1.0 GHz		178.4	225	mA

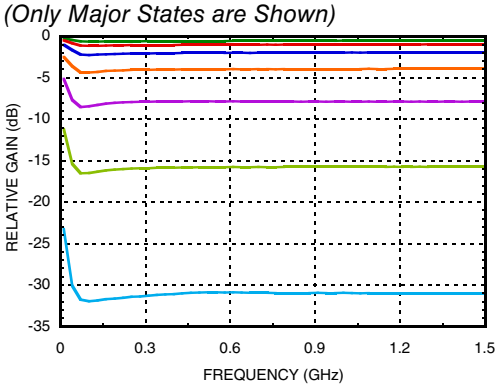
0.5 dB LSB GaAs MMIC 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 1 GHz

Gain vs. Frequency [1]



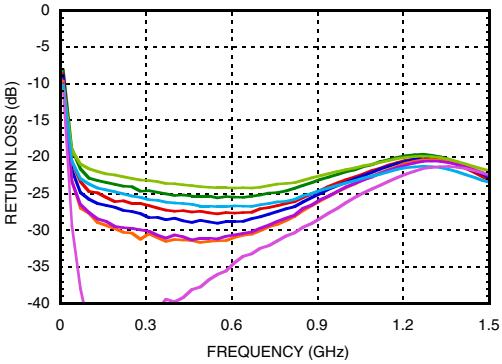
Relative Gain Setting

(Referenced to Maximum Gain State)
(Only Major States are Shown)



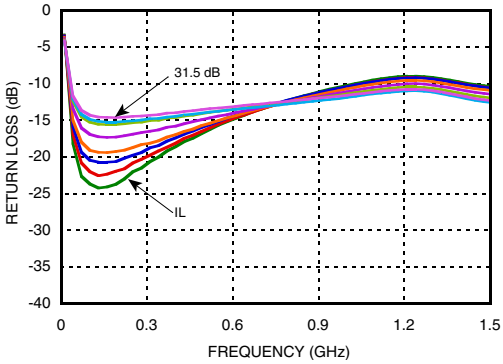
Input Return Loss [1]

(Only Major States are Shown)



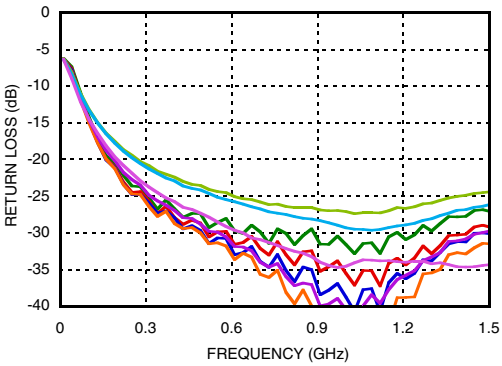
Output Return Loss [1]

(Only Major States are Shown)



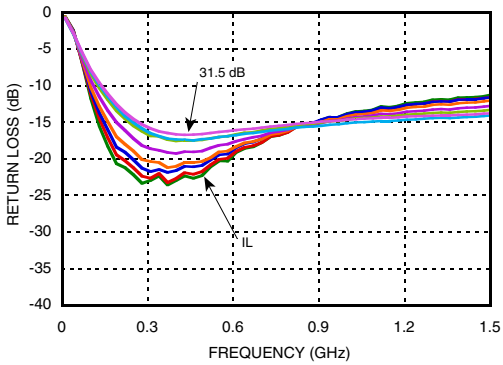
Input Return Loss [2]

(Only Major States are Shown)



Output Return Loss [2]

(Only Major States are Shown)

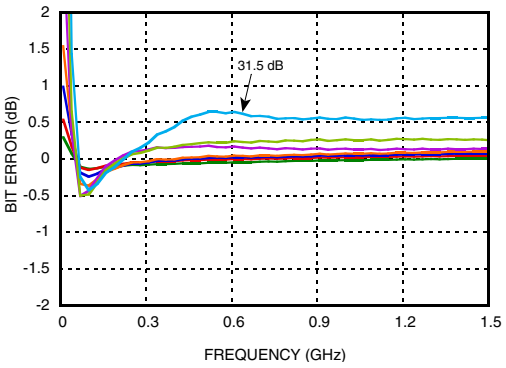


[1] Tested on eval board with broadband bias tees, C7, C8 = 10,000 pF ; L1, L2 = 680 nH
[2] Tested on eval board with broadband bias tees, C7, C8 = 330 pF ; L1, L2 = 110 nH

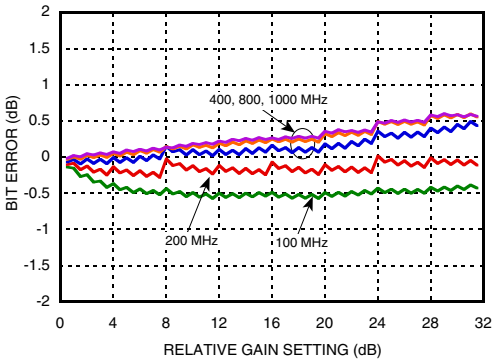
0.5 dB LSB GaAs MMIC 6-BIT DIGITAL VARIABLE GAIN AMPLIFIER, DC - 1 GHz

Bit Error vs. Frequency [2]

(Only Major States are Shown)

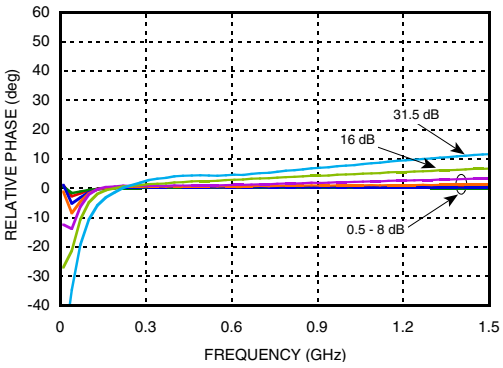


Bit Error vs. Relative Gain Setting [2]



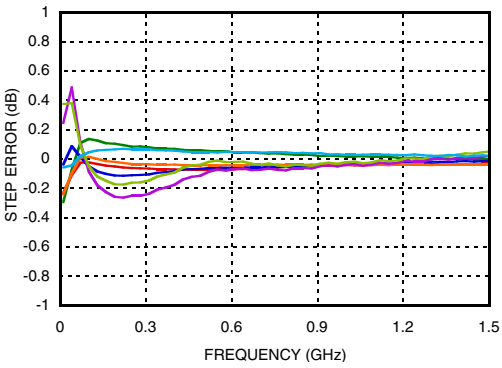
Relative Phase vs. Frequency [2]

(Only Major States are Shown)



Step Error vs. Frequency [2]

(Only Major States are Shown)



[1] Tested on eval board with broadband bias tees, C7, C8 = 10,000 pF ; L1, L2 = 680 nH
[2] Tested on eval board with broadband bias tees, C7, C8 = 330 pF ; L1, L2 = 110 nH

Bias Voltage & Current

Vdd (V)	Idd (Typ.) (mA)
+4.5	2.3
+5.0	2.4
+5.5	2.5
Vs (V)	Is (mA)
+5.0	88

Control Voltage Table

State	Vdd = +3V	Vdd = +5V
Low	0 to 0.5V @ <1 µA	0 to 0.8V @ <1 µA
High	2 to 3V @ <1 µA	2 to 5V @ <1 µA

Absolute Maximum Ratings

RF Input Power [1] (At Max Gain Setting)	-10.5 dBm (T = +85 °C)
Bias Voltage (Vdd)	+5.5 Vdc
Collector Bias Voltage (Vcc)	5.5 Vdc
Channel/Junction Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 18.2 mW/°C above 85 °C) [2]	1.18 W
Thermal Resistance [3]	55°C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

[1] The Max RF Input Power Rating will increase by 0.5 dB for every 0.5 dB reduction in gain to a maximum RF Input Power of 10 dBm.

[2] This value is the total power dissipation in the amplifier.

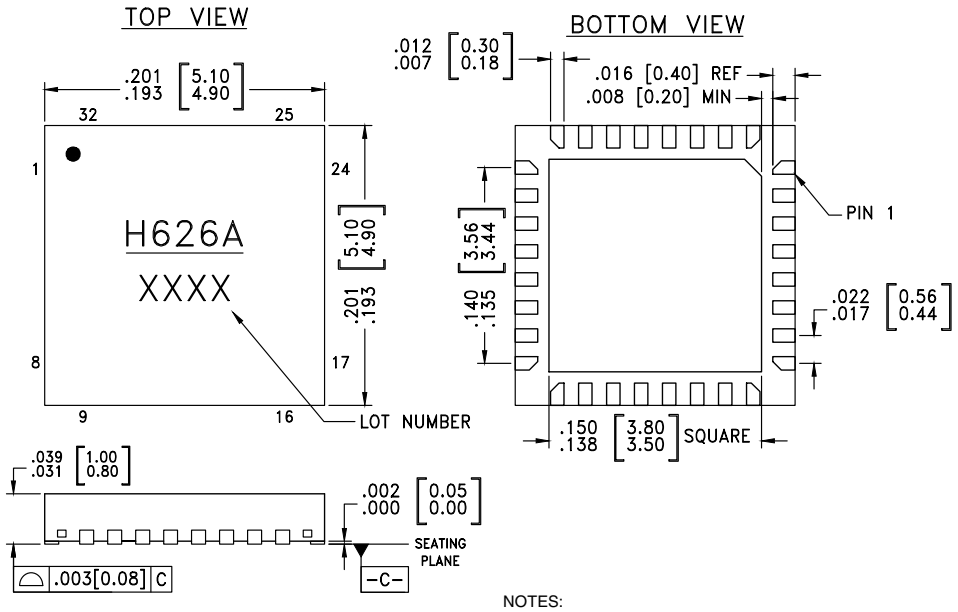
[3] This is the thermal resistance for the amplifier.

Truth Table

Control Voltage Input						Relative Gain Setting
V1 16 dB	V2 8dB	V3 4 dB	V4 2 dB	V5 1 dB	V6 0.5 dB	
High	High	High	High	High	High	Reference 0 dB
High	High	High	High	High	Low	-0.5 dB
High	High	High	High	Low	High	-1 dB
High	High	High	Low	High	High	-2 dB
High	High	Low	High	High	High	-4 dB
High	Low	High	High	High	High	-8 dB
Low	High	High	High	High	High	-16 dB
Low	Low	Low	Low	Low	Low	-31.5 dB
Any combination of the above states will provide a relative gain setting approximately equal to the sum of the bits selected.						

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

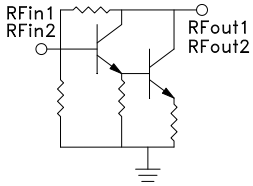
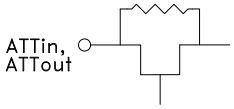
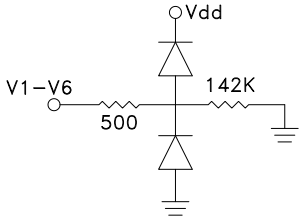
1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

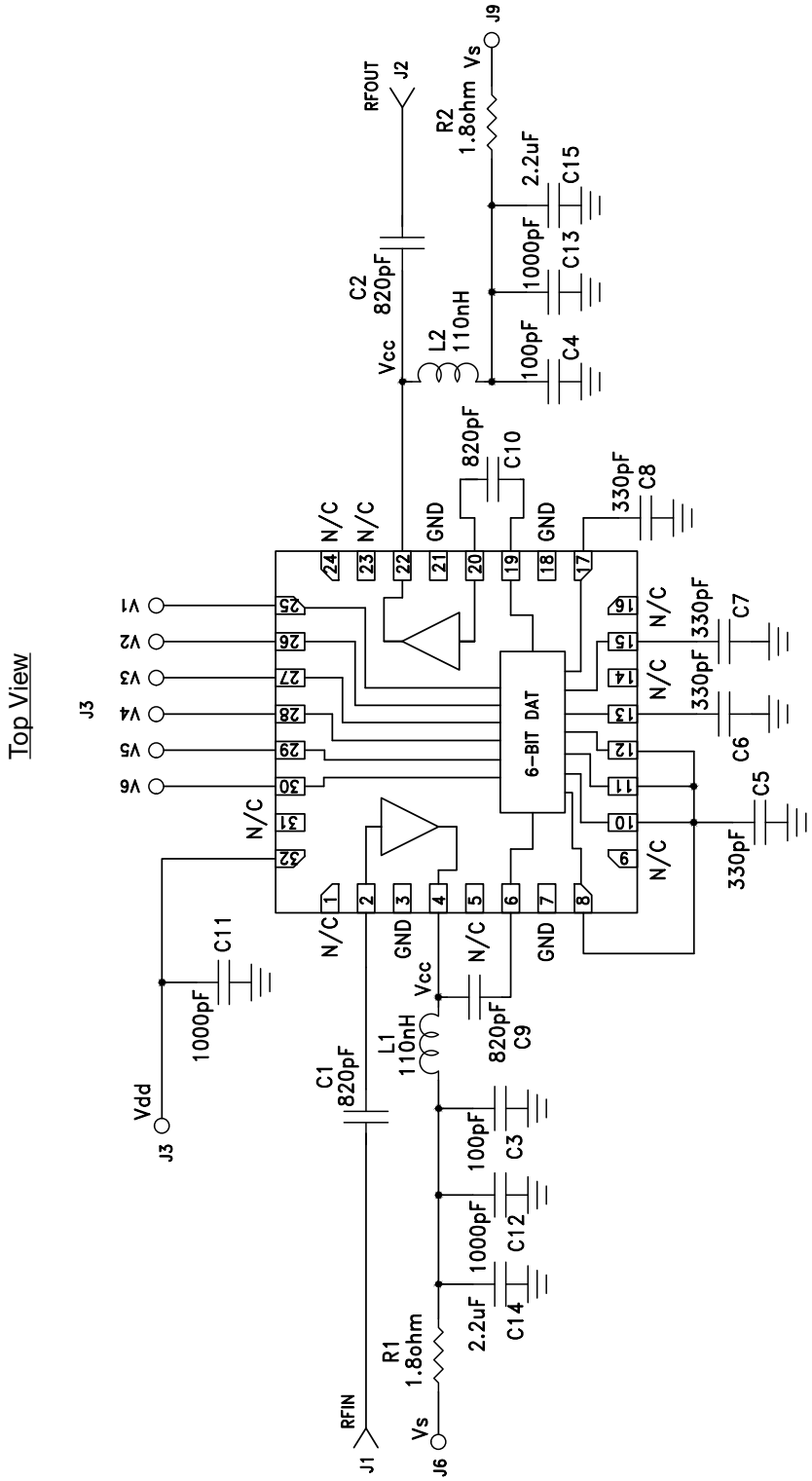
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC626ALP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [1]	H626A XXXX

[1] Max peak reflow temperature of 260 °C
[2] 4-Digit lot number XXXX

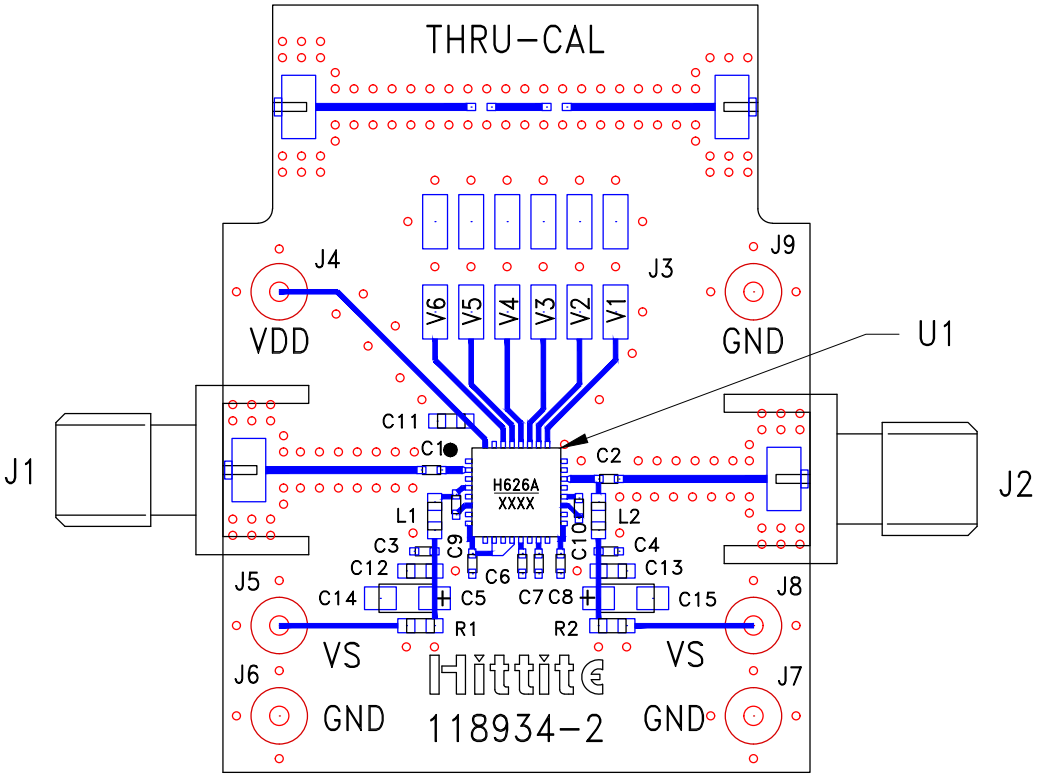
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 5, 9, 14, 16, 23, 24, 31	N/C	These pins may be connected to RF/DC ground. Performance will not be affected.	
2, 20	RFin1, RFin2	This pin is DC coupled. An off chip DC blocking capacitor is required.	
4, 22	RFout1, RFout2	RF output and DC bias (Vcc) for the output stage of the amplifiers. Amplifier bias provided via external bias tee as shown in application circuit.	
3, 7, 18, 21	GND	These pins and package bottom must be connected to RF/DC ground.	
6, 19	ATTin, ATTout	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required. Select value based on lowest frequency of operation.	
8, 10, 11, 12, 13, 15, 17	ACG1, ACG2, ACG3, ACG4, ACG5, ACG6, ACG7	External capacitors to ground is required. Select value for lowest frequency of operation. Place capacitor as close to pins as possible.	
25 - 30	V1 - V6	See truth table, control voltage table and timing diagram.	
32	Vdd	Supply voltage	

Application Circuit



Evaluation PCB



List of Materials for Evaluation PCB 117355-HMC626ALP5 [1]

Item	Description
J1 - J2	PCB Mount SMA Connector
J3	12 Pin DC Connector
J4 - J9	DC Pin
C1, C2, C9, C10	820 pF Capacitor, 0402 Pkg.
C3, C4	100 pF Capacitor, 0402 Pkg.
C5 - C8	330 pF Capacitor, 0402 Pkg.
C11 - C13	1000 pF Capacitor, 0402 Pkg.
C14, C15	2.2 µF Capacitor, CASE A Pkg.
R1, R2	1.8 Ohm Resistor, 0603 Pkg.
L1, L2	110 nH Inductor, 0603 Pkg.
U1	HMC626ALP5E Variable Gain Amplifier
PCB [2]	118934 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.